



08/355652

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Docket: 0756-1139

4/B
2-22-95
RC

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Application of)
Shunpei YAMAZAKI et al.)
Based on Serial No. 08/142,048) Art Unit: 1104
Filed: December 14, 1994) Examiner: C. Chaudhari
For: LASER PROCESSING METHOD,)
METHOD FOR FORMING A)
FLASH MEMORY, INSULATED)
GATE SEMICONDUCTOR)
DEVICE AND METHOD FOR)
FORMING THE SAME) Date: December 14, 1994

PRELIMINARY AMENDMENT

Honorable Commissioner of Patents and Trademarks
Washington, D.C. 20231

Sir:

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Cancel claim 1 and add new claims 21-52.

--21. A laser processing method comprising:
forming a gate member on a semiconductor;

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Pach.
C1

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